# **BLP5LA55S**

Power LDMOS transistor Rev. 4 — 12 January 2023

### **Product profile** 1.

## 1.1 General description

This 13.6 V 55 W device is designed for land mobile radio (LMR) applications supporting the frequency range from HF up to 520 MHz.

### Table 1. **Application performance**

Typical RF performance at T<sub>case</sub> = 25 °C; in a class-AB demo circuit.

Test signal	f	I <sub>Dq</sub>	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	η <b>D</b>	RL <sub>in</sub>
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dB)
CW	145 to 165	893	15.0	63	>23.0	>66.4	-7.8
	380 to 450	80	13.6	55	>20.4	>62.3	-6.3
	520	100	13.6	55	19.6	75.0	–15.3

## 1.2 Features and benefits

- High efficiency
- Integrated dual sided ESD protection
- Extreme ruggedness 65 : 1
- High power gain
- Excellent reliability
- Wideband
- High linearity
- For RoHS compliance see the product details on the Ampleon website

## 1.3 Applications

- TETRA, SSB and LTE mobile radio applications in VHF and UHF bands
- Wideband radio application, frequency range from 5 MHz to 30 MHz and from 30 MHz to 512 MHz

## 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		
3	source		

[1] Connected to flange.

## 3. Ordering information

### Table 3. Ordering information

Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)
TO-270-2F-1	BLP5LA55SZ	9349 602 92515	TR13; 500-fold; 24 mm; dry pack	500
	BLP5LA55SXY	9349 602 92538	TR7; 100-fold; 24 mm; dry pack	100

## 4. Limiting values

### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage		-	30	V
V <sub>GS</sub>	gate-source voltage		-5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

### Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case} = 80 \ ^{\circ}C; V_{DS} = 13.6 \ V;$ $P_{L} = 55 \ W$	0.46	K/W

## 6. Characteristics

### Table 6.DC characteristics

 $T_j = 25 \ ^{\circ}C$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; \text{ I}_{D} = 2.25 \text{ mA}$	30	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 225 \text{ mA}$	1.5	1.9	2.5	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 V; V_{DS} = 32 V$	-	-	1.4	μA
I <sub>DSX</sub>	drain cut-off current	$\label{eq:VGS} \begin{array}{l} V_{GS} = V_{GS(th)} + 3.75 \; V; \\ V_{DS} = 10 \; V \end{array}$	-	38	-	A
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nA
<b>g</b> <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 11.25 A	-	15	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance		-	60	-	mΩ

## Table 7. AC characteristics

 $T_i = 25 \ ^{\circ}C$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 V; V_{DS} = 13.6 V; f = 1 MHz$	-	173.5	-	pF
C <sub>oss</sub>	output capacitance	$V_{GS} = 0 V; V_{DS} = 13.6 V; f = 1 MHz$	-	106.1	-	pF
C <sub>rss</sub>	reverse transfer capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 13.6 V; f = 1 MHz	-	1.3	-	pF

### Table 8. RF characteristics

Test signal: CW at  $V_{DS}$  = 13.6 V;  $I_{Dq}$  = 100 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production board measured at frequencies of 520 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	P <sub>L</sub> = 55 W	18.0	19.6	-	dB
RL <sub>in</sub>	input return loss	P <sub>L</sub> = 55 W	-	-15.3	-	dB
η <sub>D</sub>	drain efficiency	P <sub>L</sub> = 55 W	72.0	75.0	-	%

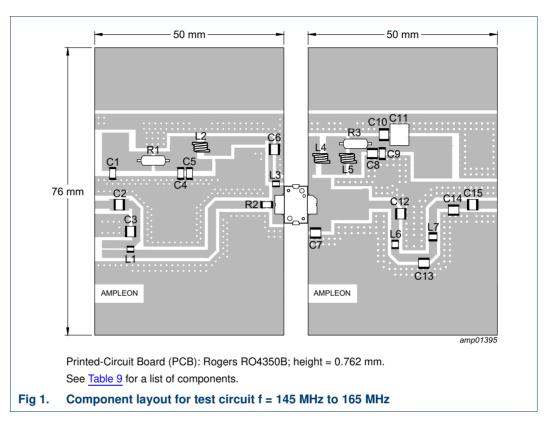
## 7. Test information

## 7.1 Ruggedness in class-AB operation

The BLP5LA55S is capable of withstanding a load mismatch corresponding to VSWR = 65 : 1 through all phases under the following conditions:  $V_{DS}$  = 13.6 V;  $I_{Dg}$  = 100 mA;  $P_L$  = 55 W (CW); f = 520 MHz.

## 7.2 Test circuit

## 7.2.1 Test circuit f = 145 MHz to 165 MHz



## Table 9.List of components

### See <u>Figure 1</u> for component layout.

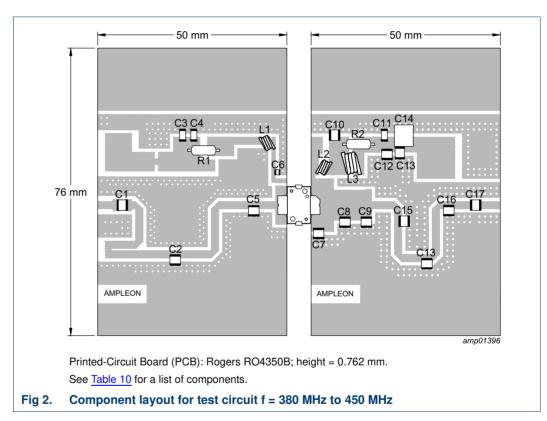
Component	Description	Value	Remarks
C1, C5, C9	multilayer ceramic chip capacitor	100 nF	C1206C104K1RAC
C2	multilayer ceramic chip capacitor	470 pF	ATC 100B
C3	multilayer ceramic chip capacitor	43 pF	ATC 100B
C4	multilayer ceramic chip capacitor	1 μF, 25 V	GRM31MR71E105KA01L
C6	multilayer ceramic chip capacitor	390 pF	ATC 100B
C7	multilayer ceramic chip capacitor	180 pF	ATC 100B
C8	multilayer ceramic chip capacitor	1 nF	ATC 100B
C10	multilayer ceramic chip capacitor	1 μF, 50 V	GRM32RR71H105KA01L
C11	multilayer ceramic chip capacitor	10 μF, 50 V	
C12	multilayer ceramic chip capacitor	200 pF	ATC 100B
C13	multilayer ceramic chip capacitor	62 pF	ATC 100B
C14	multilayer ceramic chip capacitor	33 pF	ATC 100B
C15	multilayer ceramic chip capacitor	330 pF	ATC 100B
L1	square air core inductor	8.9 nH	0806SQ-8N9JL
L2	inductor air core	~30 nH	
L3	square air core inductor	10.2 nH	0807SQ-10NJL

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## Table 9. List of components ...continued See Figure 1 for component lowout

See <u>Figure 1</u> for component layout.						
Component	Description	Value	Remarks			
L4	inductor air core	~60 nH				
L5	Inductor air core	~30 nH				
L6	wire one turn	~0.3 nH				
L7	square air core inductor	16.6 nH	0908SQ-17NJL			
R1	axial resistor	51.1 Ω				
R2	SMD	6.8 Ω	Size: 1206 (3216 metric)			
R3	axial resistor	68.1 Ω				

## 7.2.2 Test circuit f = 380 MHz to 450 MHz



### Table 10. List of components

See Figure 2 for component layout.

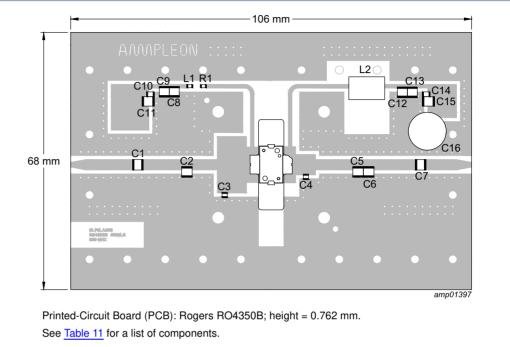
Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	240 pF	ATC 100B
C2	multilayer ceramic chip capacitor	18 pF	ATC 100B
C3	multilayer ceramic chip capacitor	1 μF, 25 V	GRM31MR71E105KA01L
C4, C11	multilayer ceramic chip capacitor	100 nF	C1206C104K1RAC
C5	multilayer ceramic chip capacitor	75 pF	ATC 100B
C6	multilayer ceramic chip capacitor	120 pF	ATC 600F
C7	multilayer ceramic chip capacitor	62 pF	ATC 800B

## Table 10. List of components ...continued

See Figure 2 for component layout.

Component	Description	Value	Remarks
C8	multilayer ceramic chip capacitor	51 pF	ATC 800B
C9	multilayer ceramic chip capacitor	43 pF	ATC 800B
C10	multilayer ceramic chip capacitor	390 pF	ATC 100B
C12	multilayer ceramic chip capacitor	1 nF	ATC 100B
C13	multilayer ceramic chip capacitor	1 μF, 50 V	GRM32RR71H105KA01L
C14	multilayer ceramic chip capacitor	10 μF, 50 V	
C15	multilayer ceramic chip capacitor	27 pF	ATC 100B
C16	multilayer ceramic chip capacitor	7.5 pF	ATC 100B
C17	multilayer ceramic chip capacitor	130 pF	ATC 100B
L1	inductor air core	~30 nH	
L2	inductor air core	~60 nH	
L3	inductor air core	~30 nH	
R1	axial resistor	68 Ω	
R2	axial resistor	10 Ω	

## 7.2.3 Test circuit f = 520 MHz

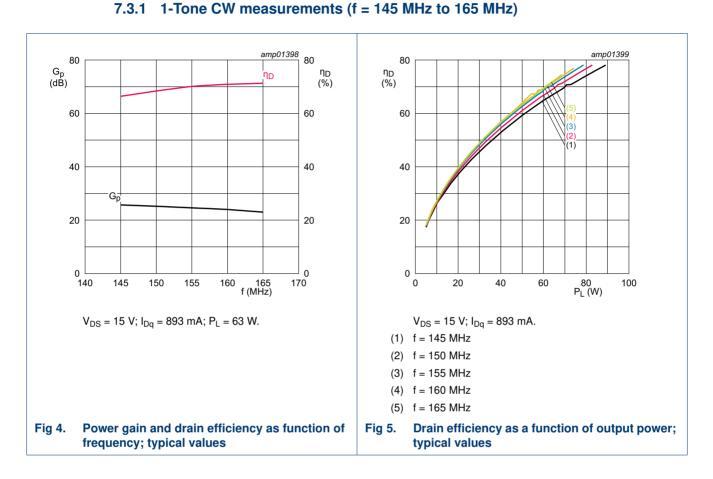


### Fig 3. Component layout for test circuit f = 520 MHz

### Table 11. List of components

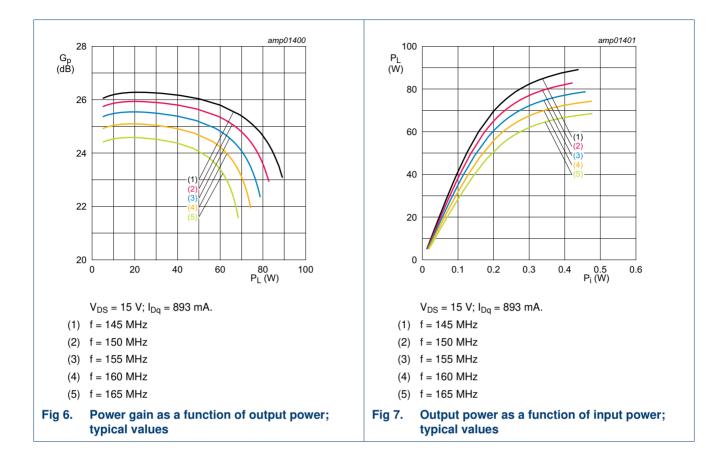
See Figure 3 for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	6.8 pF	ATC 100B
C2	multilayer ceramic chip capacitor	20 pF	ATC 100B
C3	multilayer ceramic chip capacitor	39 pF	ATC 100A
C4	multilayer ceramic chip capacitor	43 pF	ATC 100A
C5	multilayer ceramic chip capacitor	6.2 pF	ATC 100B
C6	multilayer ceramic chip capacitor	10 pF	ATC 100B
C7	multilayer ceramic chip capacitor	15 pF	ATC 100B
C8, C12	multilayer ceramic chip capacitor	22 pF	ATC 100B
C9, C13	multilayer ceramic chip capacitor	1 nF	ATC 100B
C10, C14	multilayer ceramic chip capacitor	0.1 μF	GRM21BR71H104KA01L
C11, C15	multilayer ceramic chip capacitor	1 μF	GRM32RR71H105KA01L
C16	Electrolytic capacitor	1000 μF, 63 V	
L1	Wire wound inductor	43 nH	LQW18AN43NG80
L2	Inductor air core	~53 nH	
R1	SMD	10 Ω	Size: 0603 (1608 metric)

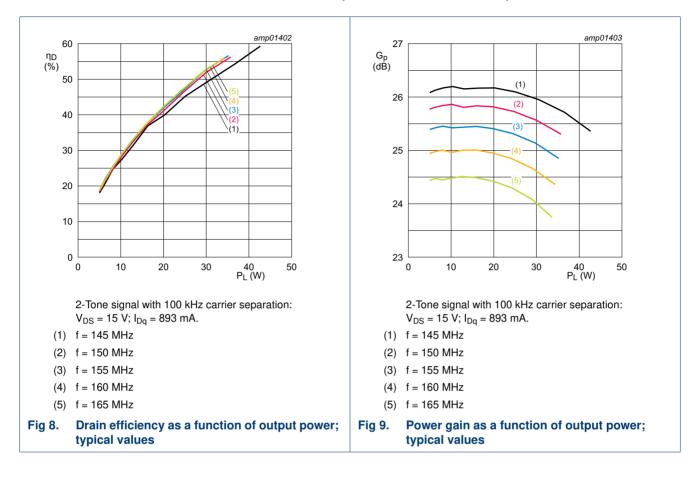


7.3 Graphical data

BLP5LA55S Power LDMOS transistor



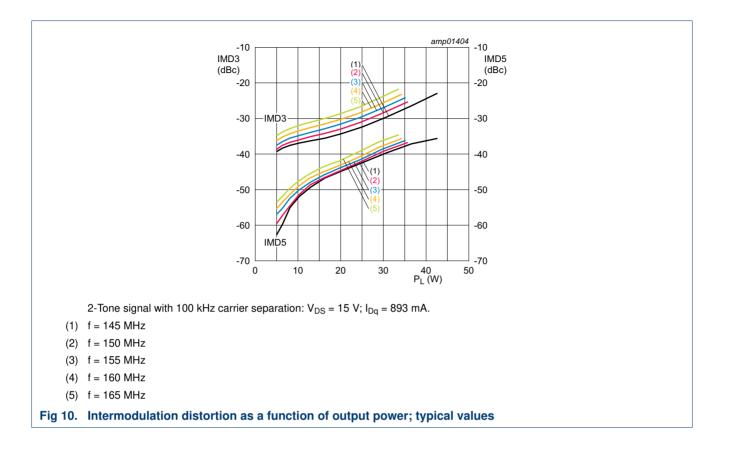
BLP5LA55S Power LDMOS transistor



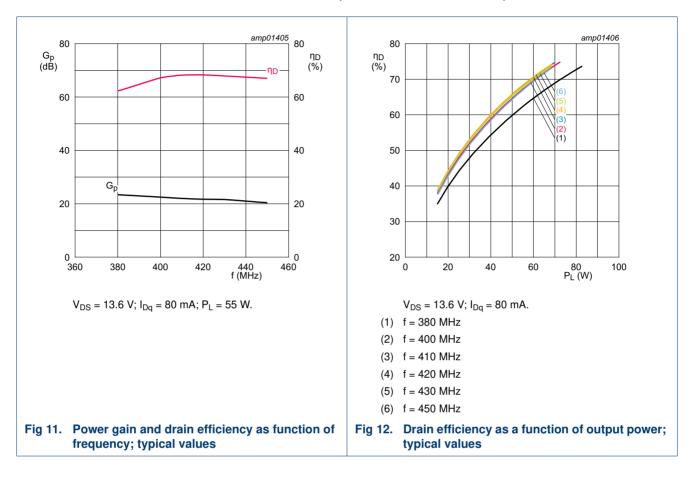
## 7.3.2 2-Tone CW measurements (f = 145 MHz to 165 MHz)

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BLP5LA55S Power LDMOS transistor



BLP5LA55S Power LDMOS transistor

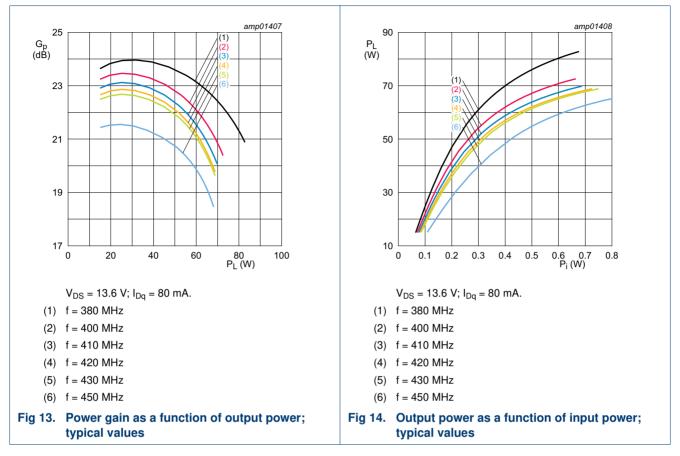


## 7.3.3 1-Tone CW measurements (f = 380 MHz to 450 MHz)

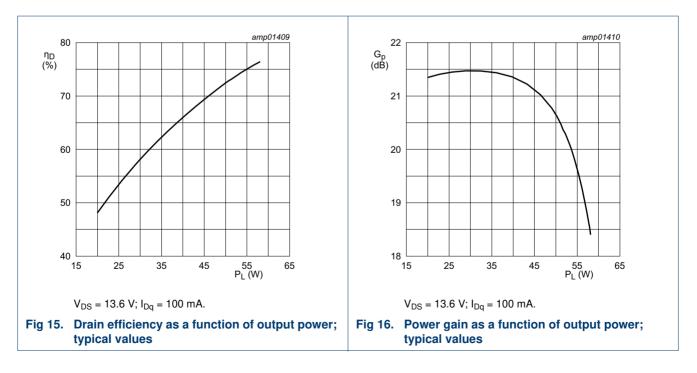
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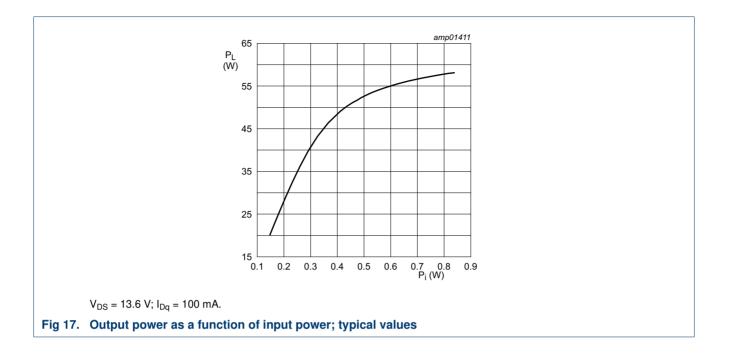
**BLP5LA55S** 



## 7.3.4 1-Tone CW measurements (f = 520 MHz)



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## 8. Package outline

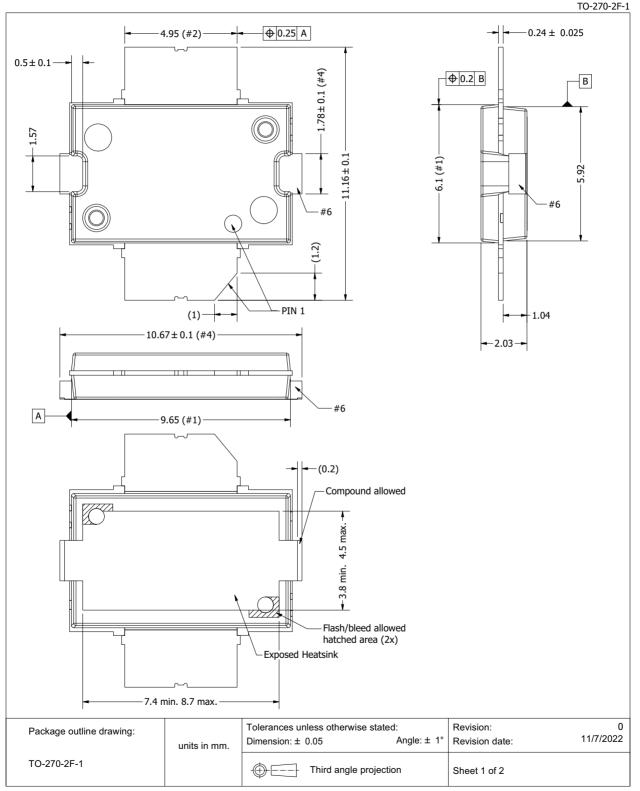


Fig 18. Package outline TO-270-2F-1 (sheet 1 of 2)

BLP5LA55S

# BLP5LA55S Power LDMOS transistor

### TO-270-2F-1

			_			
			Dra	wing Notes		
Items				Description		
(1)	Dimensions are excluding mold protrusion. The mold protrusion is maximum 0.15 mm per side. See also detail B.					
(1)	In the dambar area max. protrusion is 0.55 mm. max. in length and 0.3 mm. max. in width (4x). See also detail B.					
(2)	The lead dambar (n	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.				
(3)	The leads and expo	sed heatsink are p	plated with ma	tte Tin (Sn).		
(4)	Dimensions (Heatsi	nk ears) 10,67 and	d 1,78 do not i	nclude mouldprotrusion. Overall Ma	ax. dimensions incl. mou	ld
(4)	protrusions is 10.92	mm. (max.) and 2	2.03 mm. (max	.).		
(5)	Lead coplanarity ov	er the leads is 0,1	mm. maximur	n.		
(6)	Surfaces may rema	in unplated (not so	olderable surfa	ces).		
BRO						
	B	Lead Dan	(0.55 max)		DETAI SCALE	50 : 1
Package ou	tline drawing:	Lead Dan	nbar protru	nless otherwise stated:	SCALE	50 : 1

### Fig 19. Package outline TO-270-2F-1 (sheet 2 of 2)

## 9. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### Table 12.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A 🛄
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

## **10. Abbreviations**

Table 13. Abbreviations			
Acronym	Description		
CW	Continuous Wave		
ESD	ElectroStatic Discharge		
HF	High Frequency		
LDMOS	Laterally Diffused Metal-Oxide Semiconductor		
LTE	Long Term Evolution		
MTF	Median Time to Failure		
RoHS	Restriction of Hazardous Substances		
SSB	Single Side-Band		
SMD	Surface Mounted Device		
TETRA	TErrestrial Trunked Radio		
UHF	Ultra High Frequency		
VHF	Very High Frequency		
VSWR	Voltage Standing Wave Ratio		

## 11. Revision history

### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP5LA55S v.4	20230112	Product data sheet	-	BLP5LA55S v.3	
Modifications:	<u>Table 3 on page 2</u> : package name changed from SOT1482-1 to TO-270-2F-1				
	• Table 5 on page	2: value changed from 0.617	K/W to 0.46 K/W		
	• <u>Table 8 on page 3</u> : clerical error; corrected $V_{DS} = 32$ V to $V_{DS} = 13.6$ V in table description				
	Section 8 on page 15: package outline drawing changed from SOT1482-1 to TO-270-2F-1				
	<u>Section 12 on page 19</u> : updated section				
BLP5LA55S v.3	20210716	Product data sheet	-	BLP5LA55S v.2	
BLP5LA55S v.2	20210401	Product data sheet	-	BLP5LA55S v.1	
BLP5LA55S v.1	20210104	Product data sheet	-	-	

## 12. Legal information

## 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## 14. Contents

1	Product profile	1
1.1	General description	
1.2	Features and benefits	1
1.3	Applications	
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	2
6	Characteristics	3
7	Test information	3
7.1	Ruggedness in class-AB operation	3
7.2	Test circuit	
7.2.1	Test circuit f = 145 MHz to 165 MHz	
7.2.2	Test circuit f = 380 MHz to 450 MHz	
7.2.3	Test circuit f = 520 MHz	
7.3	Graphical data	8
7.3.1	1-Tone CW measurements (f = 145 MHz to	
	165 MHz)	8
7.3.2	2-Tone CW measurements ( $f = 145$ MHz to	
700		10
7.3.3	1-Tone CW measurements ( $f = 380$ MHz to	10
7.3.4	450 MHz) 1-Tone CW measurements (f = 520 MHz)	12 13
8		15
	-	17
9		••
10		17
11	······································	18
12	Legal information	19
12.1	Data sheet status	19
12.2	Definitions	19
12.3		19
12.4		20
13	Contact information	20
14	Contents	21

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